The MMIC VCO Design for Wireless Systems at Ka-Band

Han-Young Lee† and Wan-Sik Kim*

Abstract – Reconfigurable radio technology is needed to reconstruct frequency and modem functionality, which can be different in various regions. In addition, it makes a single mobile handset capable of supporting various standards of wireless communication and thus plays a key role in mobile convergence. An MMIC VCO (voltage controlled oscillator) has been developed for high power and wide bandwidth where Clapp-Gouriet type oscillators are adapted for series feedback, and was fabricated based on 0.15μm pHEMT of TRW. The MMIC VCO was connected to an aluminar substrate on the carrier for testing. This MMIC VCO module showed good performance in comparison to existing works. Furthermore, it can be potentially extended to reconfigure an MMIC VCO for wireless systems such as military applications and satellite communications.

Keywords: Clapp-Gouriet type, MMIC VCO, Wireless systems, Communication, Handset

1. Introduction

Reconfigurable radio technology has recently attracted much interest from researchers because it makes a mobile terminal to support various communication requirements, such as different frequencies and modems, which are needed for communication environments. High frequency, stability and tunable low noise oscillators are key components for achieving high performance, and low cost Millimeter-Wave (MMW) applications such as wireless communications and automotive radar systems [1-3]. Several oscillators operating at millimeter-wave frequencies using high electron mobility transistor (HEMT) technology have been reported [4]-[6]. The design goal of an MMIC VCO is increasing output power and bandwidth. For the purpose of this goal, the Clapp-Gouriet type is adapted for a series feedback oscillator [7]-[8].

In this paper, the design specifications of a VCO are shown in Table 1.

It is fabricated by 0.15μm pHEMT foundry of TRW. The developed MMIC VCO can be used for target sensing in poor environments such as wireless communication systems, radar and anti-collision radar for cars. It can also be applicable to wireless systems such as military applications and satellite communications.

Table 1. The Specifications of an MMIC VCO.

<table>
<thead>
<tr>
<th>Specifications</th>
<th>Design Goals</th>
</tr>
</thead>
<tbody>
<tr>
<td>Oscillation freq. [GHz]</td>
<td>35</td>
</tr>
<tr>
<td>Tuning Bandwidth [GHz]</td>
<td>&gt;1.5</td>
</tr>
<tr>
<td>Output Power [dBm]</td>
<td>&gt;10</td>
</tr>
<tr>
<td>Phase Noise [dBc/Hz]@1MHz</td>
<td>-100</td>
</tr>
<tr>
<td>Harmonics [dBc]</td>
<td>&lt;30</td>
</tr>
<tr>
<td>Bias Voltage [V]</td>
<td>3</td>
</tr>
<tr>
<td>Tuning Voltage [V]</td>
<td>3~9</td>
</tr>
</tbody>
</table>

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2. Design and Fabrication

2.1 Design of an MMIC VCO based on a Clapp-Gouriet Oscillator

The basic schematic of a Clapp type oscillator is shown in Fig. 1. Most RF oscillators can be explained as feedback circuits, the magnitude of loop gain to keep continuous oscillator conditions should be the unity and phase difference of the loop have to be zero. That is,

\[ \Gamma_{IN}(j\omega) \Gamma_{L}(j\omega) = 1 \]  \hspace{1cm} (1)

Also, an LC tank is included to ensure a stable frequency. The basic concept of the Clapp-Gouriet oscillator consists of parallel inductance and capacitance, and the LC tank impedance is real and phase difference is zero when oscillation begins. The bias condition is Vdd=3V (Id=24.25mA), Vgg=-0.1V for the oscillator, and output load impedance is selected for maximum output power in Fig. 2.
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Oscillation occurs when \( s11 \) is greater than 1. If it appears less than 1, a feedback inductance of 0.5nH is added to the open stub as the series feedback at FET Source for the purpose of \( |\Gamma|>1 \). Fig. 3 shows the simulation results of the reflection coefficient that the real value of \( S11(-1.813+j0.937) \) is larger than 1 in the Smith chart [9]-[10].

The inductance value in the resonance circuit should be decided upon for the oscillation frequency of the VCO circuit. The resonance condition for oscillation is \( XL(o) = -XIN(o) \) and inductance (L1) at 35GHz is selected as 0.367nH and inductance (L2) is 0.308nH as shown in Fig. 4.

Characteristic impedance is simulated in Fig. 5. As a result, the oscillation condition is satisfied that the real part of impedance has \(-439\) at 35GHz and the imaginary part has almost zero.

To achieve a good output power for the oscillation, the negative resistance looking into the collector of PHEMT devices is designed to be about three times that of the resistance looking into the output load. That is,

\[-R_L(w)+jX_L(w) = -R_IN(w)/3-jX_IN(w)\]  \( (2) \)

The results of the simulation are shown in Fig. 6. The oscillation frequency of 34.73GHz and the output power of 10.76dBm when the DC bias condition is \( V_{dd}=3V \) (\( I_d=24.25mA \)), \( V_{gg}=-0.1V \), and the harmonic suppression is excellent at more than \(-30dBc\). The tuning range of the frequency with varactor voltage from 4V to 8V is shown in Fig. 7. The frequency is tuned from 34.5GHz to 36.5GHz, with an approximate bandwidth of 2GHz, and the output power is shown from 8.5GHz to 11.5GHz. The simulation results are shown the phase noise of \(-100dBc/Hz\) at 1MHz offset in Fig. 8.
3. Measured Results

3.1 Assembling the VCO

Kovar is used to carrier in VCO module and the 50 ohm. Also, alumina substrate is used for the output port of the VCO MMIC. An isolator with 20dB isolation characteristics is used to minimize the reflection of the VCO output power and is assembled with 0.7 mm diameter thickness wire bonding to minimize the transmitting power loss for each of the components shown in Fig. 10.

A detailed illustration of the VCO module is shown in Fig. 11, and is assembled with an MMIC, alumina substrate, isolator and probe point.

3.2 Test Results

The VCO test results, such as frequency and power of 11.06dBm, are very similar to the simulation results showing a frequency of 34.73GHz and power of 11.06dBm in Fig. 12.

The non-linearity is less than 13% when the voltage range of the varactor is from 3V to 8V, as shown in Fig. 13.

The test results showed phase noise of –90.27dBc/Hz at 1MHz offset in Fig. 14, and so reached the design goal of -100dBc/Hz at 1MHz offset at the bias condition.
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Fig. 14. Phase noise photograph of the MMIC VCO.

The VCO is assembled on a carrier fabricated with eutectic and epoxy bonding, with no carrier for biasing. Also, 0.7 mil wire bonding and 10 mil ribbon bonding are used to assemble the VCO. It requires careful fabrication skills as the tolerance error must have an influence on the system characterization [11].

Test results, such as for output power and bandwidth, show a good performance compared to the previous paper. We can see the test results in Table 2 [12]-[13].

Table 2. Test results compared with the previous paper.

<table>
<thead>
<tr>
<th>Specifications</th>
<th>This paper</th>
<th>Pervious paper[12]</th>
<th>Pervious paper[13]</th>
</tr>
</thead>
<tbody>
<tr>
<td>Oscillation freq.[GHz]</td>
<td>35</td>
<td>38</td>
<td>40</td>
</tr>
<tr>
<td>Tuning Band width[GHz]</td>
<td>&gt;2.2</td>
<td>&gt;0.85</td>
<td>&gt;2.0</td>
</tr>
<tr>
<td>Output Power[dBm]</td>
<td>8.5-11.5</td>
<td>9-10.5</td>
<td>2-6</td>
</tr>
<tr>
<td>Phase Noise[dBc/Hz]</td>
<td>-90.27</td>
<td>-108</td>
<td>-95</td>
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<tr>
<td>Harmonics[dBc]</td>
<td>&lt;30</td>
<td>-</td>
<td>-</td>
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<tr>
<td>Bias Voltage[V]</td>
<td>3</td>
<td>3.5V</td>
<td>3.5</td>
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<tr>
<td>Tuning Voltage [V]</td>
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<td>0-4</td>
<td>0-4</td>
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<tr>
<td>Device</td>
<td>pHEMT</td>
<td>InGaAs</td>
<td>InP HBT</td>
</tr>
</tbody>
</table>

4. Conclusion

In this paper, an MMIC VCO for Ka-Band is designed and assembled using a 0.15um pHEMT foundry of TRW. A Clapp-Gouriet type oscillator is used for series feedback in the MMIC VCO for the purpose of high output power and wide bandwidth. The VCO Module is manufactured in a small and integrated size, which is assembled on the carrier using wire and ribbon bonding with only a 0.2dB insertion loss. The designed MMIC VCO was assembled for testing as a module and the test results showed a frequency of 35GHz, a tuning bandwidth of about 2.2GHz and output power of 11.5dBm. However, although it was designed as -100dBc/Hz at 1MHz offset, the phase noise was tested -90dBc/Hz at 1MHz offset. Both of the test results of output power and bandwidth show a good performance compared to previous papers.

The MMIC VCO developed can be used for target sensing in bad environments such as wireless communication systems, radar and anti-collision radars for cars. Also, it is useful for wireless systems such as military applications and satellite communication systems.

References

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